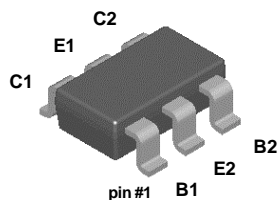


FMB100



SuperSOT™-6
Mark: .NA
Dot denotes pin #1

NPN Multi-Chip General Purpose Amplifier

This device is designed for general purpose amplifier applications at collector currents to 300 mA. Sourced from Process 10.

Absolute Maximum Ratings*

$T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Value | Units |
|----------------|--|-------------|------------------|
| V_{CEO} | Collector-Emitter Voltage | 45 | V |
| V_{CBO} | Collector-Base Voltage | 75 | V |
| V_{EBO} | Emitter-Base Voltage | 6.0 | V |
| I_C | Collector Current - Continuous | 500 | mA |
| T_J, T_{stg} | Operating and Storage Junction Temperature Range | -55 to +150 | $^\circ\text{C}$ |

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Characteristic | Max | Units |
|-----------------|---|--------|---------------------------|
| | | FMB100 | |
| P_D | Total Device Dissipation Derate above 25°C | 700 | mW |
| | | 5.6 | mW/ $^\circ\text{C}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 180 | $^\circ\text{C}/\text{W}$ |

NPN Multi-Chip General Purpose Amplifier

(continued)

FMB100

Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Units |
|----------------------------|--------------------------------------|----------------------------------|-----|-----|-----|-------|
| OFF CHARACTERISTICS | | | | | | |
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C = 10\ \mu\text{A}, I_B = 0$ | 75 | | | V |
| BV_{CEO} | Collector-Emitter Breakdown Voltage* | $I_C = 1\ \text{mA}, I_E = 0$ | 45 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10\ \mu\text{A}, I_C = 0$ | 6.0 | | | V |
| I_{CBO} | Collector Cutoff Current | $V_{CB} = 60\ \text{V}$ | | | 50 | nA |
| I_{CES} | Collector Cutoff Current | $V_{CE} = 40\ \text{V}$ | | | 50 | nA |
| I_{EBO} | Emitter Cutoff Current | $V_{EB} = 4\ \text{V}$ | | | 50 | nA |

ON CHARACTERISTICS

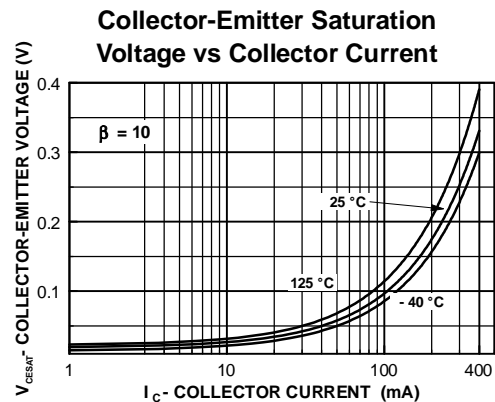
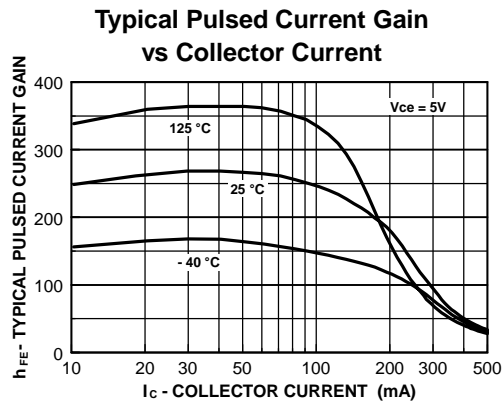
| | | | | | | |
|---------------|--------------------------------------|---|-------------------------|--|-------------|--------|
| h_{FE} | DC Current Gain | $I_C = 100\ \mu\text{A}, V_{CE} = 1.0\ \text{V}$ $I_C = 10\ \text{mA}, V_{CE} = 1.0\ \text{V}$ $I_C = 100\ \text{mA}, V_{CE} = 1.0\ \text{V}^*$ $I_C = 150\ \text{mA}, V_{CE} = 5.0\ \text{V}^*$ | 80 100 100 100 | | 450 350 | |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = 10\ \text{mA}, I_B = 1.0\ \text{mA}$ $I_C = 200\ \text{mA}, I_B = 20\ \text{mA}^*$ | | | 0.2 0.4 | V V |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage | $I_C = 10\ \text{mA}, I_B = 1.0\ \text{mA}$ $I_C = 200\ \text{mA}, I_B = 20\ \text{mA}^*$ | | | 0.85 1.0 | V V |

SMALL SIGNAL CHARACTERISTICS

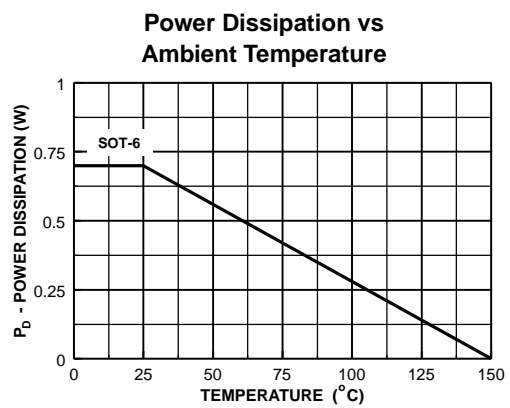
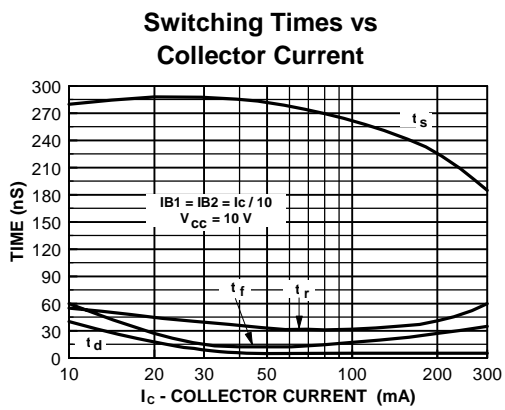
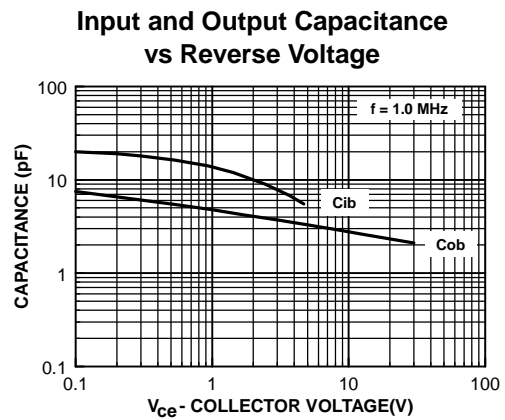
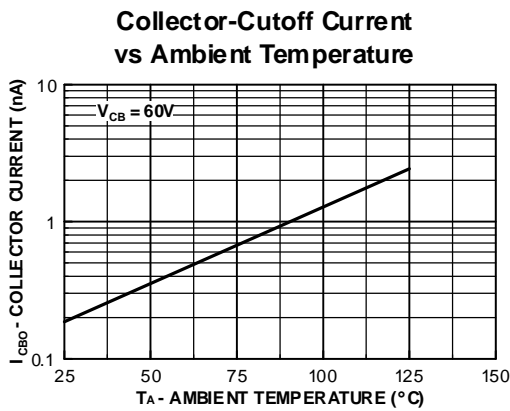
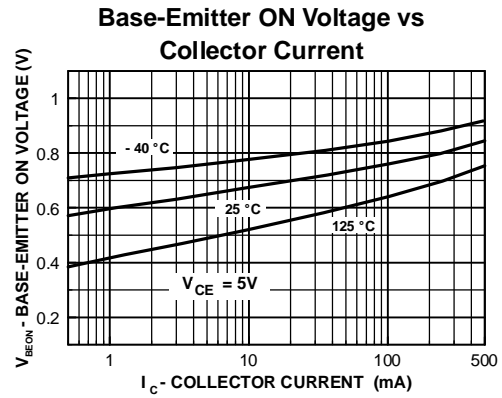
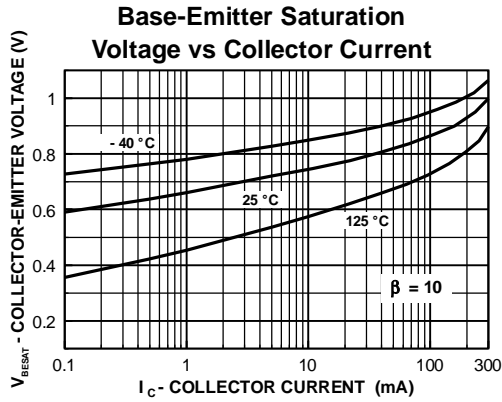
| | | | | | | |
|-----------|----------------------------------|---|--|-----|--|-----|
| f_T | Current Gain - Bandwidth Product | $V_{CE} = 20\ \text{V}, I_C = 20\ \text{mA}$ | | 300 | | MHz |
| C_{obo} | Output Capacitance | $V_{CB} = 5.0\ \text{V}, f = 1.0\ \text{MHz}$ | | 3.5 | | pF |
| NF | Noise Figure | $I_C = 100\ \mu\text{A}, V_{CE} = 5.0\ \text{V},$ $R_G = 2.0\ \text{k}\Omega, f = 1.0\ \text{kHz}$ | | 2.5 | | dB |

*Pulse Test: Pulse Width $\leq 300\ \mu\text{s}$, Duty Cycle $\leq 2.0\%$

Typical Characteristics



Typical Characteristics (continued)



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